

Vishay Siliconix

# N-Channel 200 V (D-S) MOSFET

#### **DESCRIPTION**

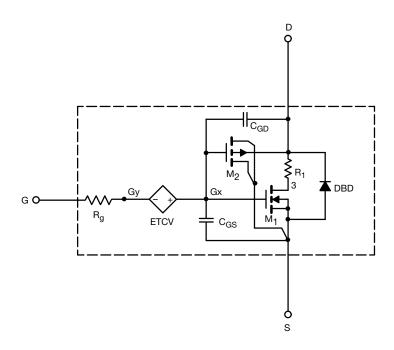
The attached SPICE model describes the typical electrical characteristics of the n-channel vertical DMOS. The sub-circuit model is extracted and optimized over the -55  $^{\circ}$ C to +125  $^{\circ}$ C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched  $C_{\rm gd}$  model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

#### **CHARACTERISTICS**

- N-Channel Vertical DMOS
- Macro Model (Sub-circuit Model)
- Level 3 MOS
- · Apply for both Linear and Switching Application
- Accurate over the -55 °C to +125 °C Temperature Range
- Model the Gate Charge

#### SUBCIRCUIT MODEL SCHEMATIC



#### Note

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer
to the appropriate datasheet of the same number for guaranteed specification limits.



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<b>SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	3	-	٧
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = 10 \text{ V}, I_D = 30 \text{ A}$	0.0137	0.0138	Ω
		$V_{GS} = 7.5 \text{ V}, I_D = 30 \text{ A}$	0.0142	0.0141	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{DS} = 15 \text{ V}, I_D = 30 \text{ A}$	77	75	S
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> = 10 A	0.8	0.8	V
Dynamic <sup>b</sup>					
Input Capacitance	C <sub>iss</sub>	$V_{DS} = 50 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	4220	4160	pF
Output Capacitance	C <sub>oss</sub>		1350	1190	
Reverse Transfer Capacitance	C <sub>rss</sub>		65	30	
Total Gate Charge	Qg		62	64	
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = 100 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 60 \text{ A}$	16.7	16.7	nC
Gate-Drain Charge	$Q_{gd}$		16.9	16.9	

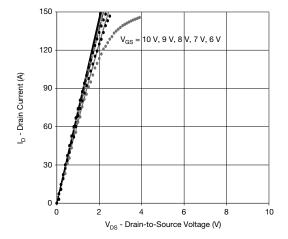
#### Notes

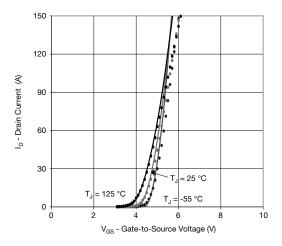
- a. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %.
- b. Guaranteed by design, not subject to production testing.

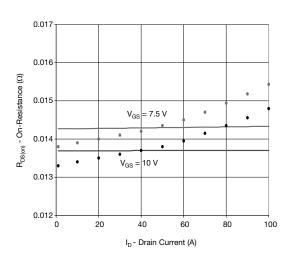
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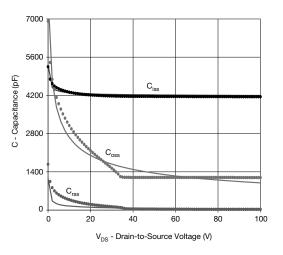
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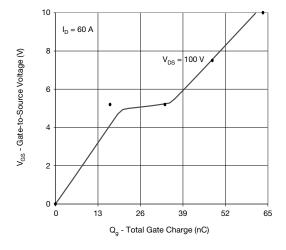
### **COMPARISON OF MODEL WITH MEASURED DATA** ( $T_J = 25$ °C, unless otherwise noted)

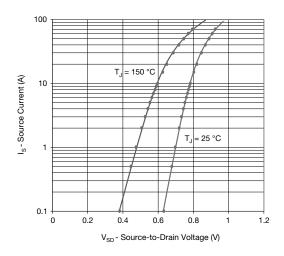












#### Note

Dots and squares represent measured data.
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